

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Side wettable flanks for optical solder inspection
- Ultra small and leadless SMD plastic package: 1.1 x 1 x 0.48 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 1 kV HBM (Class H1C)
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Tubic 1. Quick I	oronomoo data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-16	-	16	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	720	mA
Static characte	ristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 720 mA; T _j = 25 °C		-	635	850	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source	3	
3	D	drain	Transparent top view DFN1110D-3 (SOT8015)	G G S 017aaa255

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
2N7002KQB	DFN1110D-3	plastic, leadless extremely thin small outline package with side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; 1.1 mm x 1 mm x 0.48 mm body	SOT8015			

7. Marking

Table 4. Marking codes	
Type number	Marking code
2N7002KQB	C7

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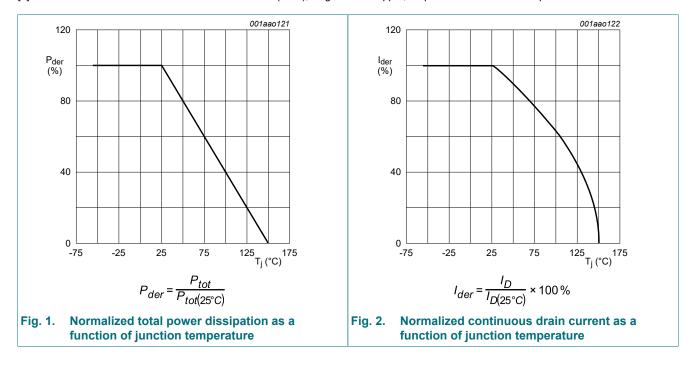
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-16	16	V
V _{GSMlim}	peak gate-source voltage	$\delta_{factor} = 0.1; t_p = 50 \ \mu s; T_j = 25 \ ^{\circ}C$		-20	20	V
ID	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	720	mA
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	460	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2.9	А
P _{tot} 1	total power dissipation	T _{amb} = 25 °C	[2]	-	420	mW
			[1]	-	960	mW
		T _{sp} = 25 °C		-	4.2	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	n diode				-	
I _S	source current	T _{amb} = 25 °C	[1]	-	700	mA
ESD maximu	um rating		I			
V _{ESD}	electrostatic discharge voltage	НВМ		-	1000	V
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)} = 25 \text{ °C}; I_D = 0.05 \text{ A}$		-	1.5	mJ
	1	1				

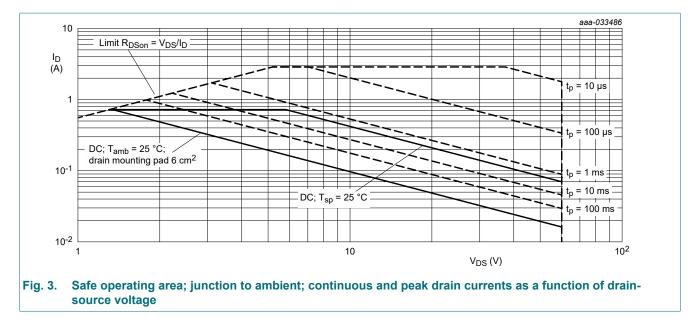
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



Product data sheet

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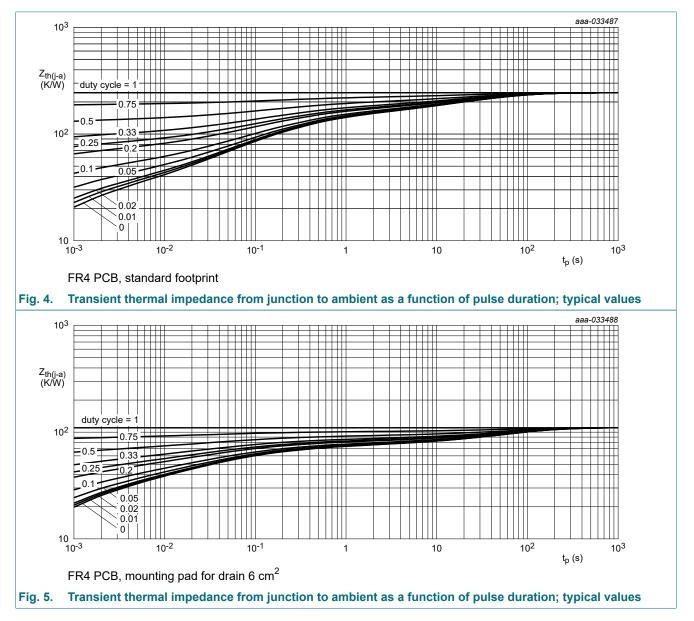
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9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from	in free air	[1]	-	245	300	K/W	
	junction to ambient		[2]	-	110	130	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	25	30	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

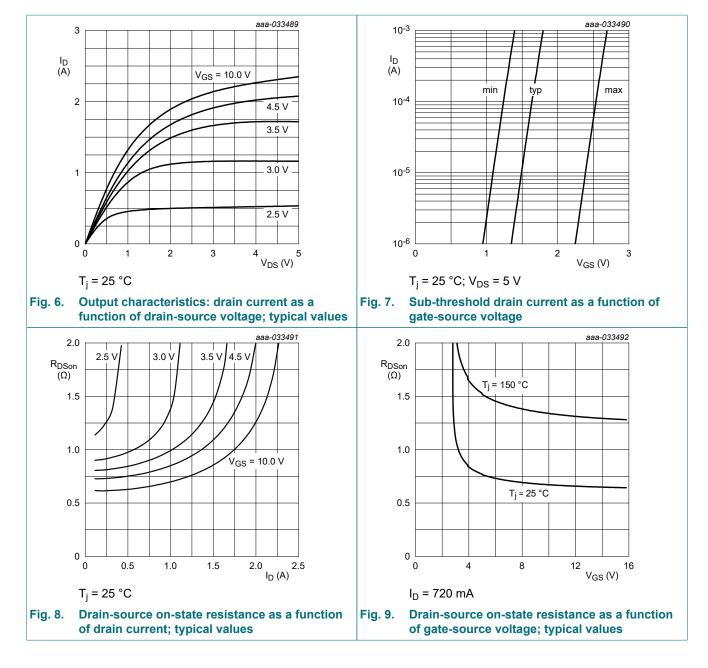
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	1.3	1.7	2.6	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 720 mA; T _j = 25 °C	-	635	850	mΩ
	resistance	V _{GS} = 10 V; I _D = 720 mA; T _j = 150 °C	-	1400	1800	mΩ
		V _{GS} = 4.5 V; I _D = 630 mA; T _j = 25 °C	-	765	1100	mΩ
9 _{fs}	forward transconductance	V _{DS} = 5 V; I _D = 720 mA; T _j = 25 °C	-	1.1	-	S
Dynamic ch	aracteristics		I			
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I_{D} = 0.7 A; V_{GS} = 10 V;	-	0.61	0.92	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.07	-	nC
Q _{GD}	gate-drain charge		-	0.15	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	28	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	5	-	pF
C _{rss}	reverse transfer capacitance		-	3	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I _D = 0.7 A; V _{GS} = 10 V;	-	1	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	1	-	ns
t _{d(off)}	turn-off delay time		-	6	-	ns
t _f	fall time		-	3	-	ns
Source-drai	in diode	· · ·				
V _{SD}	source-drain voltage	I _S = 0.7 A; V _{GS} = 0 V; T _j = 25 °C	-	0.7	1.2	V
t _{rr}	reverse recovery time	$ I_{\rm S} = 0.7 \text{ A}; dI_{\rm S}/dt = -100 \text{ A/s}; \\ V_{\rm GS} = 10 \text{ V}; V_{\rm DS} = 30 \text{ V}; T_{\rm j} = 25 ^{\circ}\text{C} $	-	8	-	ns
Q _r	recovered charge	I _S = 0.7 A; dI _S /dt = -100 A/µs; V _{GS} = 10 V; V _{DS} = 30 V; T _i = 25 °C	-	2	-	nC

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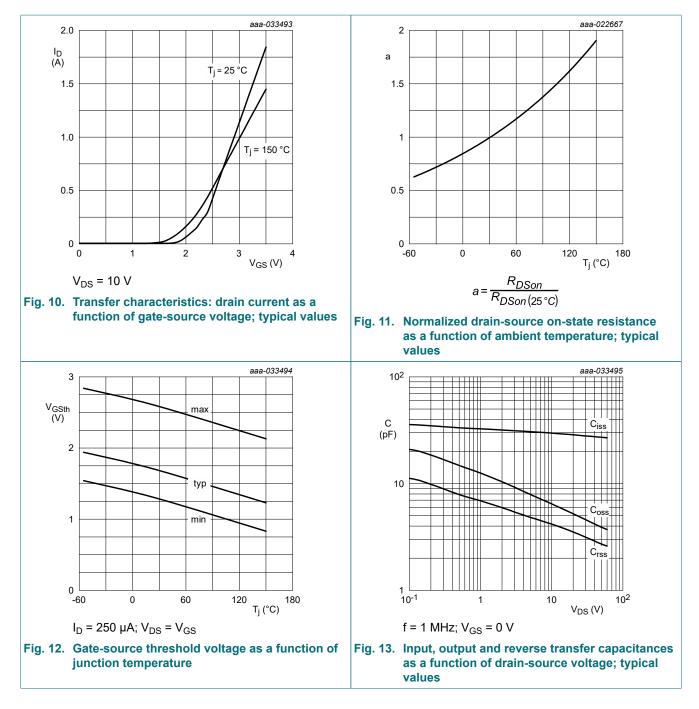


Product data sheet

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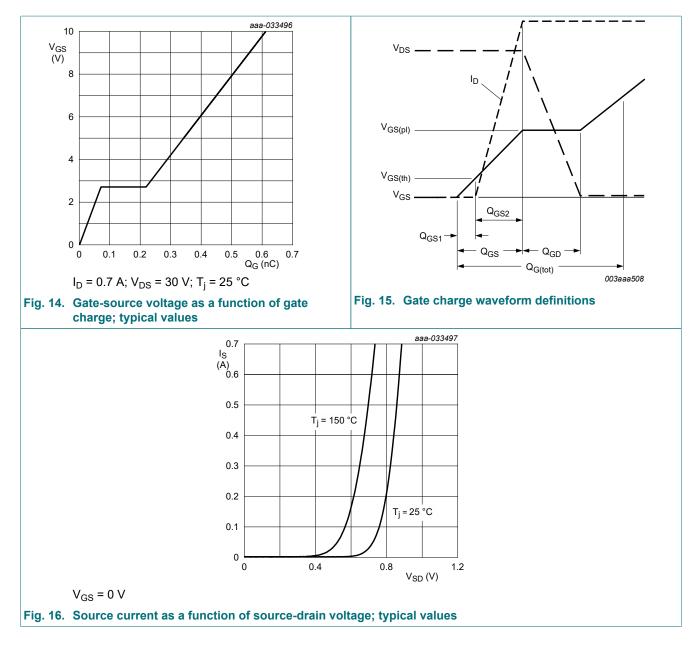
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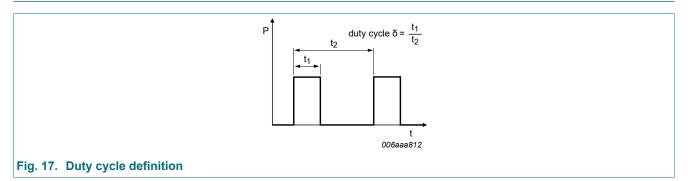


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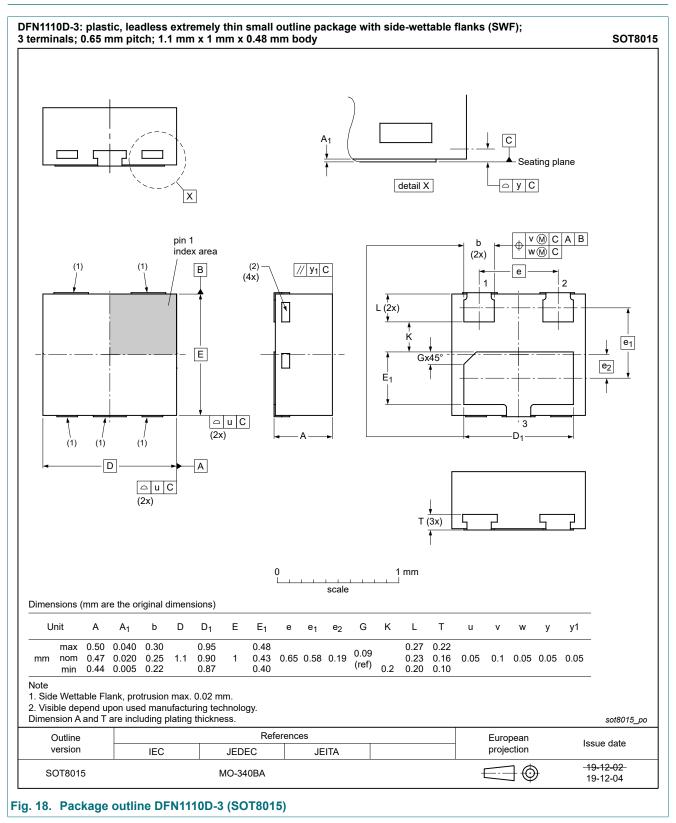
11. Test information



Quality information

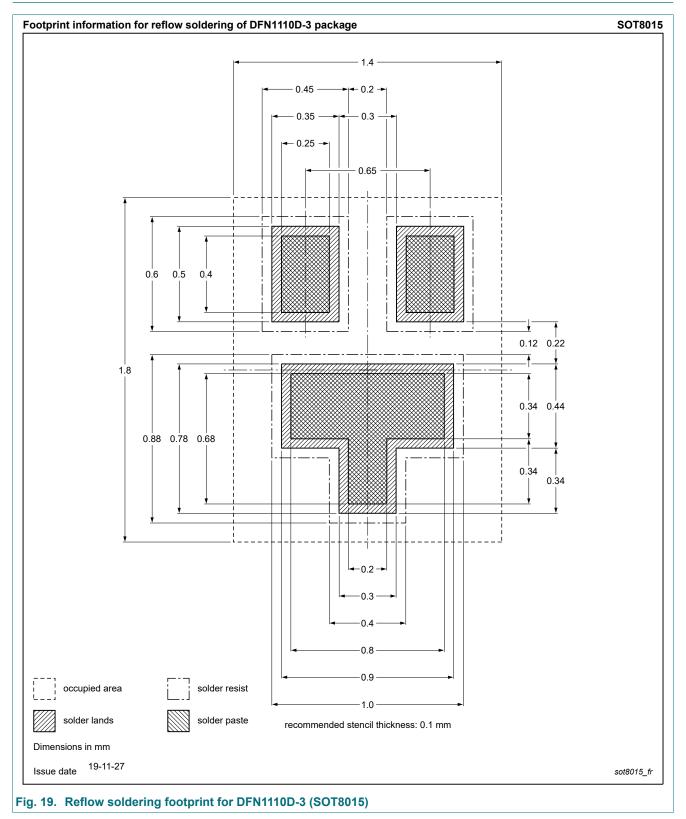
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
2N7002KQB v.1	20210922	Product data sheet	-	-		

2N7002KQB

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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